

TOSHIBA BI-DIRECTIONAL TRIODE THYRISTOR SILICON PLANAR TYPE

**SM8G48, USM8G48, SM8J48, USM8J48**  
**SM8G48A, USM8G48A, SM8J48A, USM8J48A**

## AC POWER CONTROL APPLICATIONS

- Repetitive Peak Off-State Voltage:  $V_{DRM} = 400V, 600V$
- R.M.S On-State Current:  $I_T (RMS) = 8A$
- Gate Trigger Current:  $I_{GT} = 30mA \text{ Max.}$   
 $\qquad\qquad\qquad : I_{GT} = 20mA \text{ Max. ("A"Type)}$

Unit: mm

SM8G48, SM8J48, SM8G48A, SM8J48A		USM8G48, USM8J48, USM8G48A, USM8J48A	
<p>1. T1</p> <p>2. T2</p> <p>3. GATE</p>		<p>1. T1</p> <p>2. T2 (BACK SIDE)</p> <p>3. GATE</p>	
JEDEC	—	JEDEC	—
JEITA	—	JEITA	—
TOSHIBA	13-10J1A	TOSHIBA	13-10J2A

Weight: 1.7g

## ABSOLUTE MAXIMUM RATINGS

CHARACTERISTIC		SYMBOL	RATING	UNIT
Repetitive Peak Off-State Voltage	(U)SM8G48	$V_{\text{DRM}}$	400	V
	(U)SM8G48A			
	(U)SM8J48 (U)SM8J48A		600	
R.M.S On-State Current		$I_{\text{T}} \text{ (RMS)}$	8	A
Peak One Cycle Surge On-State Current (Non-Repetitive)		$I_{\text{TSM}}$	80 (50Hz)	A
			88 (60Hz)	
$I^2t$ Limit Value		$I^2t$	32	$\text{A}^2\text{s}$
Critical Rate of Rise of On-State Current (Note 1)		$di / dt$	50	A / $\mu\text{s}$
Peak Gate Power Dissipation		$P_{\text{GM}}$	5	W
Average Gate Power Dissipation		$P_{\text{G}} \text{ (AV)}$	0.5	W
Peak Forward Gate Voltage		$V_{\text{GM}}$	10	V
Peak Forward Gate Current		$I_{\text{GM}}$	2	A
Junction Temperature		$T_{\text{j}}$	-40~125	°C
Storage Temperature Range		$T_{\text{stg}}$	-40~125	°C

Note 1:  $V_{\text{DRM}} = 0.5 \times \text{Rated}$

$$I_{\text{TM}} \leq 12\text{A}$$

$$t_{\text{gw}} \geq 10\mu\text{s}$$

$$t_{\text{gr}} \leq 250\text{ns}$$

$$I_{\text{gp}} = I_{\text{GT}} \times 2.0$$

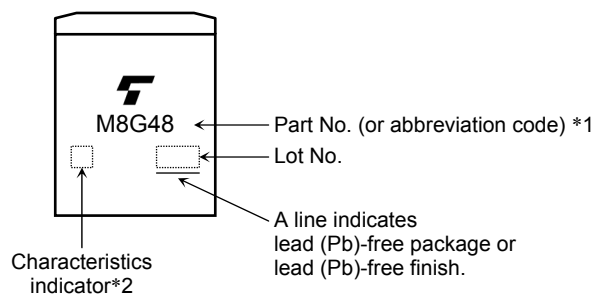
Note 2: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

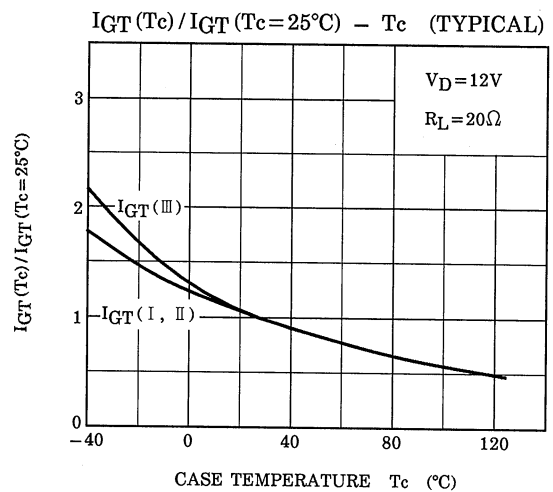
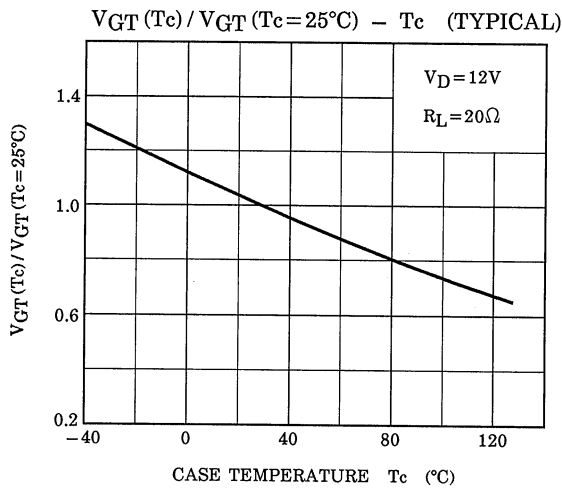
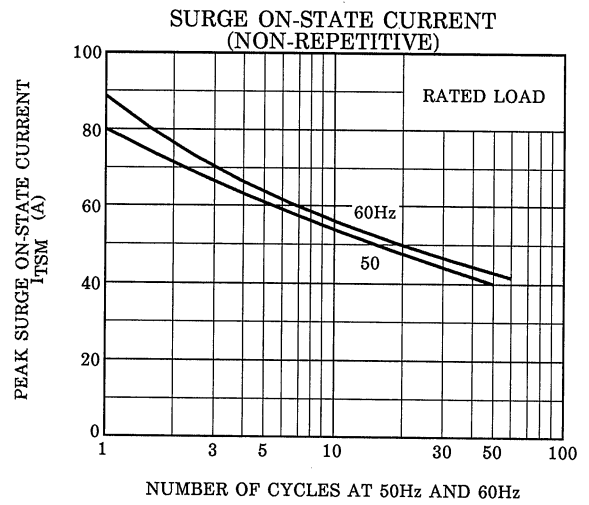
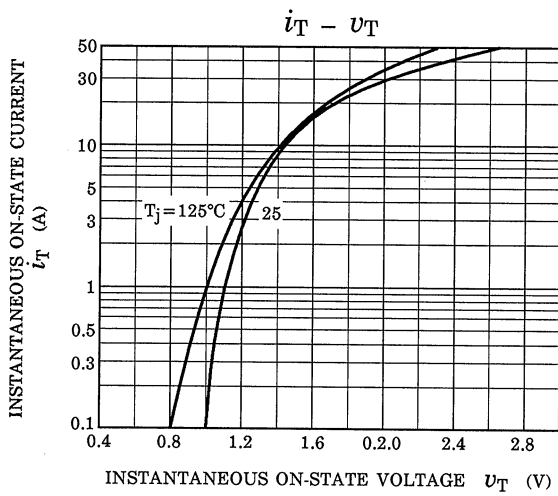
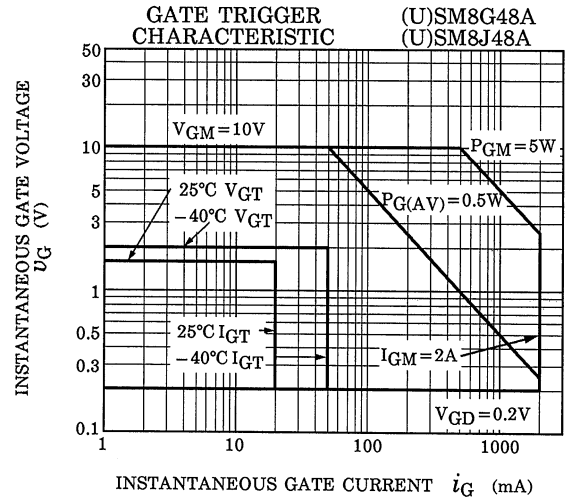
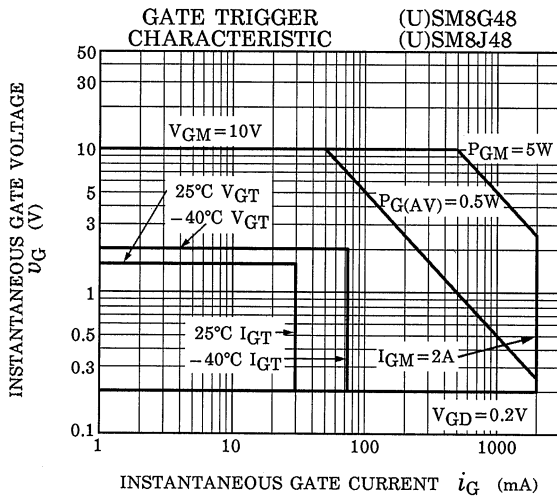
## ELECTRICAL CHARACTERISTICS (Ta = 25°C)

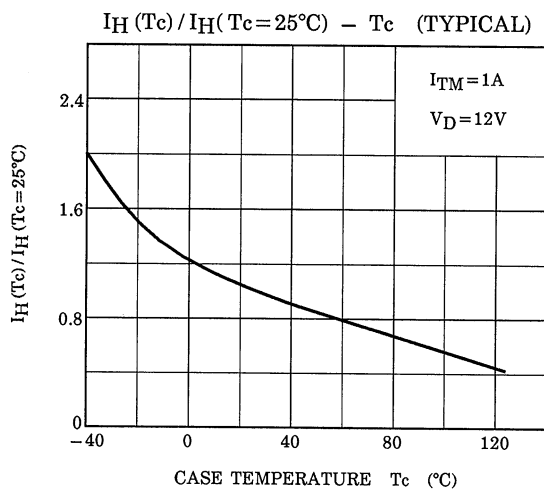
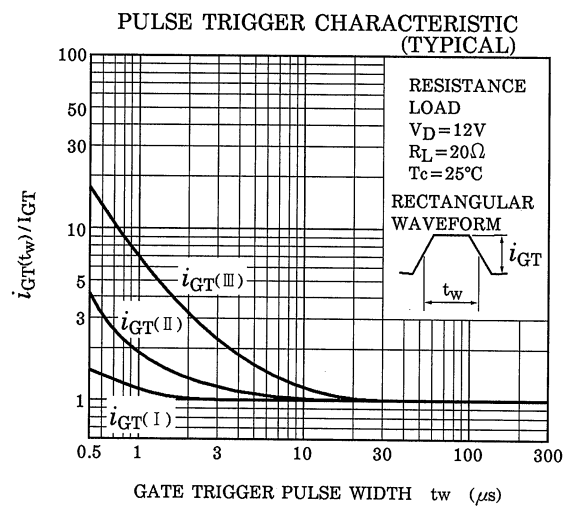
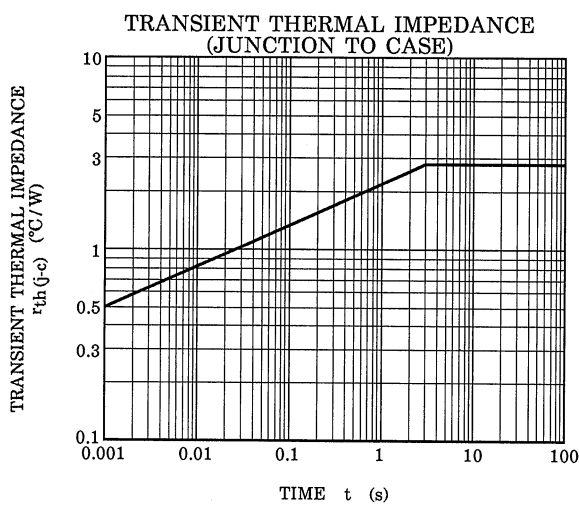
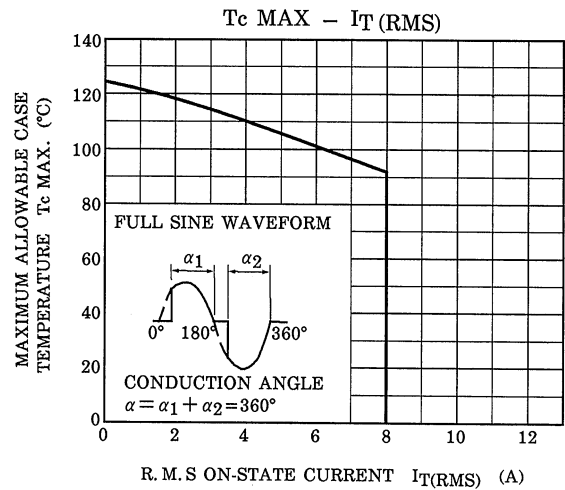
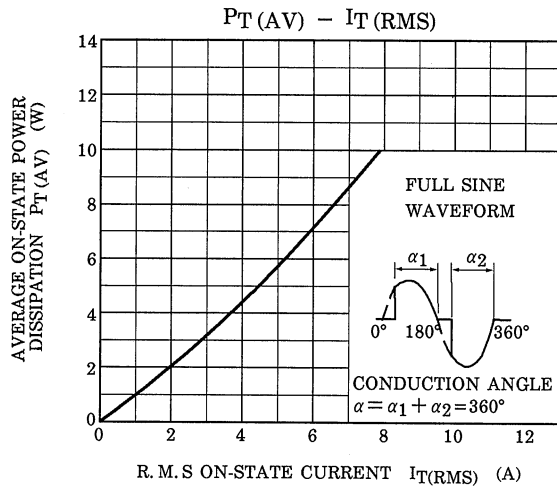
CHARACTERISTIC		SYMBOL	TEST CONDITION		MIN	TYP.	MAX	UNIT	
Repetitive Peak Off-State Current		I <sub>DRM</sub>	V <sub>DRM</sub> = Rated		—	—	20	μA	
Gate Trigger Voltage		I	V <sub>GT</sub>	V <sub>D</sub> = 12V R <sub>L</sub> = 20Ω	T2 (+), Gate (+)	—	—	1.5	V
		II			T2 (+), Gate (–)	—	—	1.5	
		III			T2 (–), Gate (–)	—	—	1.5	
		IV			T2 (–), Gate (+)	—	—	—	
Gate Trigger Current	(U)SM8G48 (U)SM8J48	I	I <sub>GT</sub>	V <sub>D</sub> = 12V R <sub>L</sub> = 20Ω	T2 (+), Gate (+)	—	—	30	mA
		II			T2 (+), Gate (–)	—	—	30	
		III			T2 (–), Gate (–)	—	—	30	
		IV			T2 (–), Gate (+)	—	—	—	
	(U)SM8G48A (U)SM8J48A	I			T2 (+), Gate (+)	—	—	20	
		II			T2 (+), Gate (–)	—	—	20	
		III			T2 (–), Gate (–)	—	—	20	
		IV			T2 (–), Gate (+)	—	—	—	
Peak On-State Voltage		V <sub>TM</sub>	I <sub>TM</sub> = 12A		—	—	1.5	V	
Gate Non-Trigger Voltage		V <sub>GD</sub>	V <sub>D</sub> = Rated, T <sub>c</sub> = 125°C		0.2	—	—	V	
Holding Current		I <sub>H</sub>	V <sub>D</sub> = 12V, I <sub>TM</sub> = 1A		—	—	50	mA	
Thermal Resistance		R <sub>th</sub> (j-c)	Junction to Case, AC		—	—	2.8	°C / W	
Critical Rate of Rise of Off-State Voltage	(U)SM8G48 (U)SM8J48	dv / dt	V <sub>DRM</sub> = Rated, T <sub>j</sub> = 125°C Exponential Rise		—	300	—	V / μs	
	(U)SM8G48A (U)SM8J48A				—	200	—		
Critical Rate of Rise of Off-State Voltage at Commutation	(U)SM8G48 (U)SM8J48	(dv / dt) c	V <sub>DRM</sub> = 400V, T <sub>j</sub> = 125°C (di / dt) c = -4.5A / ms		10	—	—	V / μs	
	(U)SM8G48A (U)SM8J48A				4	—	—		

## MARKING



	Part No. (or abbreviation code)	Part No.
*1	M8G48	SM8G48, SM8G48A
		USM8G48, USM8G48A
	M8J48	SM8J48, SM8J48A
		USM8J48, USM8J48A
*2	Nothing	SM8G48, SM8J48
		USM8G48, USM8J48
	A	SM8G48A, SM8J48A
		USM8G48A, USM8J48A





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